

A Nickel-Based Semiconductor Hybrid Material with Significant Dielectric Constant for Electronic Capacitors

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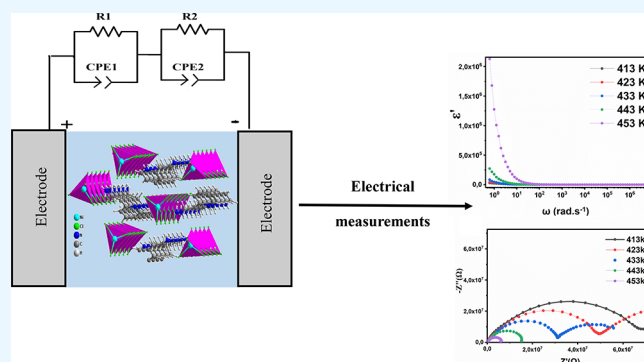
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ABSTRACT: A novel semiconducting Ni(II)-based hybrid material with the formula $(C_7H_{12}N_2)_NiCl_4$, which exhibits interesting optical and electrical properties, is reported. The crystal structure was investigated using SCXRD, whereas physical properties were studied by means of thermal analysis, Ft-Infrared, optical, and electrical measurements. Its crystal packing is formed through organic rings surrounded by inorganic $[NiCl_4]^{2-}$ tetrahedral and stacked along the *a*-crystallographic axis. This arrangement is stabilized by a dense network of intermolecular hydrogen bonds. The investigated compound displayed a wide absorption range across the visible spectrum, characterized by an optical gap energy of 2.64 eV, indicating its semiconducting nature and efficient sunlight absorption capabilities across various wavelengths. Such features are of utmost importance in achieving a high energy conversion efficiency in solar cell applications. Further analyses of the thermal behavior using differential scanning calorimetry revealed a single-phase transition occurring at around 413 K, which was further confirmed through electrical measurements. A deep investigation of the electric and dielectric performances demonstrated a significant dielectric constant ($\epsilon' \sim 10^4$) at low frequencies and low dielectric loss at high frequencies. Thus, it highlights its exceptional dielectric potential, particularly in applications related to electronic capacitors.



1. INTRODUCTION

In our pursuit of a sustainable future, electronic capacitors have emerged as fundamental building blocks of modern electronic systems, revolutionizing various aspects of our daily lives. These versatile components have played a crucial role in advancing technology and enabling the development of highly integrated circuits, efficient energy systems, and sophisticated electronic devices. Electronic capacitors have become crucial in a variety of electronic devices that have become essential to our modern society, such as computers, smartphones, and even integrated circuits.^{1–6}

Significant progress has been made in the field of capacitors through the development of semiconducting materials such as silicon,^{7,8} graphene,^{9,10} carbon nanotubes,^{11,12} and so on. Among these new materials, hybrid compounds have demonstrated exceptional physical properties, including tenability, high electron mobility, low thermal conductivity, improved performance, and lower production costs. These materials offer the advantage of incorporating, within the same atomic architecture, both organic and inorganic properties. This combination results in multifunctional materials that integrate useful properties within a single composite, opening up a broad range of technological applications.^{13–16}

The unique characteristics of halide-based hybrid materials have sparked considerable interest in their potential in various fields. Their remarkable properties have paved the way for advancements in electronics and other technological domains and opened new frontiers in light detectors, quantum computing, and memory devices.^{14–21} Aside from these fascinating electrical characteristics, these crystalline materials have exhibited compelling optical properties, expanding the range of potential applications, especially in optoelectronics and photovoltaic solar cells.^{22–27} By taking advantage of the physical properties of the different entities that form hybrid materials, researchers are exploring new frontiers in the development of advanced systems.^{28–33}

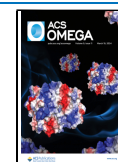
In 2023, A.Ghoudi's group synthesized a 0D hybrid material with the formula $C_6H_9N_2FeCl_4$.³⁴ The semiconducting nature of this compound was verified through optical-absorption measurements, revealing a band gap of approximately 2.47 eV.

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At low frequencies, this material exhibits a notable dielectric constant, reaching values of around 10^6 , which signifies that the synthesized material is a good candidate for electrical energy storage applications.

Within this context, our research groups designed, in 2023, a low-dimensional and eco-friendly Ni(II)-based hybrid material, namely $[(C_3H_7)_4N] Ni_2Cl_6$ ³⁵ that demonstrated interesting semiconducting properties with an optical gap energy of 3.72 eV, making it an excellent candidate for photovoltaic applications, particularly in solar cell technology. The reported $(H_2AMP)_2[Fe^{III}Br_4] Br_3$ ³⁶ (AMP: 2-(ammoniomethyl)-pyridinium) hybrid material revealed an optical band gap of 1.06 eV, which promoted efficient energy conversion processes. In 2021, R. Kalthoum and coauthors reported two hybrid materials, $(CH_3NH_3) CdCl_3$ and $(CH_3)_2NH_2CdCl_3$ ³⁷ that demonstrated good electric properties for capacitor devices with dielectric constants, reaching values of 10^3 at low frequencies and high electrical conductivity of approximately $2.10^{-4} S.m^{-1}$, along with a low dielectric loss of less than 0.1 at high frequencies. While some halide-based hybrid materials are ideal for use in electronic devices, they face limitations due to their low dielectric constants and the instability of their molecular frameworks during electrical measurements, which limit their application in certain systems.

In continuation of the above groundbreaking research efforts aimed at improving these findings, we report a novel semiconductor Ni(II)-based hybrid compound with the formula $(C_7H_{12}N_2) NiCl_4$. Its crystal structure, thermal (TGA and DSC) profiles, and spectroscopic features were studied. Additionally, the synthesized hybrid material was optically and electrically evaluated in order to gain insights into the semiconducting properties and electric mechanisms as well as to confirm the phase transition observed in thermal analysis.

2. EXPERIMENTAL SECTION

Chemical reagents, including 2-(2-aminoethyl) pyridine ($C_7H_{10}N_2$, 95%) and nickel(II) chloride hexahydrate ($NiCl_2 \cdot 6H_2O$, 99%), were acquired from a commercial source (Sigma-Aldrich) and used as received without purification.

2.1. Sample Preparation. Green crystals of $(C_7H_{12}N_2) NiCl_4$ were obtained through the slow evaporation technique of an aqueous solution containing 2-(2-aminoethyl) pyridine and nickel chloride hexahydrate in 1:2 molar ratios at room temperature. The reactants were dissolved in a small amount of distilled water and stirred briefly, while hydrochloric acid (HCl) was gradually added dropwise to it. After 1 week, the crystals were collected via filtration and air-dried.

2.2. Instruments. **2.2.1. Single Crystal X-ray Diffraction.** A suitable crystal of Ni(II) halide-based material was chosen and examined under a polarizing microscope before being mounted on a Bruker APEX II diffractometer with Mo- $K\alpha$ radiation. The data collected spanned an angular range of $1.9^\circ \leq \theta \leq 30.2^\circ$, and a total of 40027 reflections were recorded, among which 2893 reflections had an intensity of $I > 2\sigma(I)$.

The crystal structure was solved in the monoclinic system with the space group $P2_1/c$ using the SHELXS-97³⁸ program within the WINGX software.³⁹ Nickel atoms were fixed with the Patterson method, while other atoms were found through Fourier calculations and refined using the SHELXL-2018⁴⁰ program with anisotropic thermal parameters. Hydrogen atoms were positioned by using a riding model. After several refinements, the final reliability factors are $R_1 = 0.032$, and

$wR_2 = 0.071$. The Diamond program⁴¹ was used to draw packing figures.

Table S1 gathers the crystallographic details of the structure refinement process for the Ni(II)-hybrid material. Tables S2 and S3 provide atomic positional parameters and anisotropic factors, respectively. Interatomic distances and bond angles are listed in Table S4.

2.2.2. TGA-DSC Measurements. The sample weighing 2.351 mg was carried out for thermogravimetric analysis (TGA) under an oxygen atmosphere with a linear heating rate of $10^\circ C/min$. The analysis was carried out within a temperature range of 303–773 K. Additionally, a differential scanning calorimetry (DSC) measurement was conducted on a sample weighing 5800 mg using a “DSC 822P METTLER TOLEDO” type device. The measurement was performed at a heating rate of $10^\circ C/min$ within a temperature range of 243–623 K.

2.2.3. Thin-Film Preparation. The spin-coating technique was used to prepare the Co(II)-based material's thin film. The crystals were spin-coated onto a solid quartz substrate for 10 s at a speed of 2500 rpm after being dissolved in 1 mL of distilled water. An annealing process at $80^\circ C$ was used to remove any residual solvent from the resultant film.

Using spin-coated sheets, optical-absorption measurements (OA) of the sample were performed at room temperature using a standard UV-vis spectrophotometer (HITACHI, U3300).

2.2.4. Electrical Measurements. Electrical measurements were conducted on a polycrystalline sample by forming it into a pellet using a uniaxial hydraulic press. The resulting pellet had a diameter of approximately 8 mm and a thickness of 1.3 mm. The pellet was then positioned between two platinum electrodes. The complex impedance spectra were subsequently recorded within a frequency range spanning from 1 Hz to 1 MHz using a TEGAM 3550 ALF automatic bridge. The measurements were performed while gradually heating the sample from 333 to 453 K.

3. RESULTS AND DISCUSSION

3.1. Crystallographic Features. The SCXRD study reveals that the investigated compound crystallizes in centrosymmetric space group $P2_1/c$, featuring a 2D framework in the sense that the crystal packing is made of discrete entities of $C_7H_{12}Cl_4N_2$ and $NiCl_4$. As reported in Figure S1, the asymmetric unit is composed of a diprotonated 2-(2-aminoethyl) pyridine group and one $[NiCl_4]^{2-}$ tetrahedron. We noticed that all atoms occupy a general position with a Wyckoff site of (4e). The projection of the crystal structure, as presented in Figure 1a, reveals an infinite pseudolayers comprising $[NiCl_4]^{2-}$ anions and organic groups, both linked by a network of hydrogen bonds to confer a 2D character to the intermolecular interaction topology. The nickel atom exhibits tetrahedral coordination, surrounded by four chlorine atoms, conferring a slightly distorted tetrahedron (inset of Figure 1b).

The average values of the axial Ni–Cl bond length are 2.269(6) Å, while the equatorial Ni–Cl bond lengths range from 2.272(7) to 2.274(6) Å. The Cl–Ni–Cl bite angles vary between 105.78(2) and 113.72(2)°. These values are in good agreement with those observed in the $[(C_3H_7)_4N] Ni_2Cl_6$ ³⁵ perovskite compound, where the Ni–Cl bond distances are in the range 2.205(5) and 2.324(5) Å and the Cl–Ni–Cl bond angles range from 85.55(19) to 147.67(3)°. It is worth noting that the $[NiCl_4]^{2-}$ groups are separated by a minimum

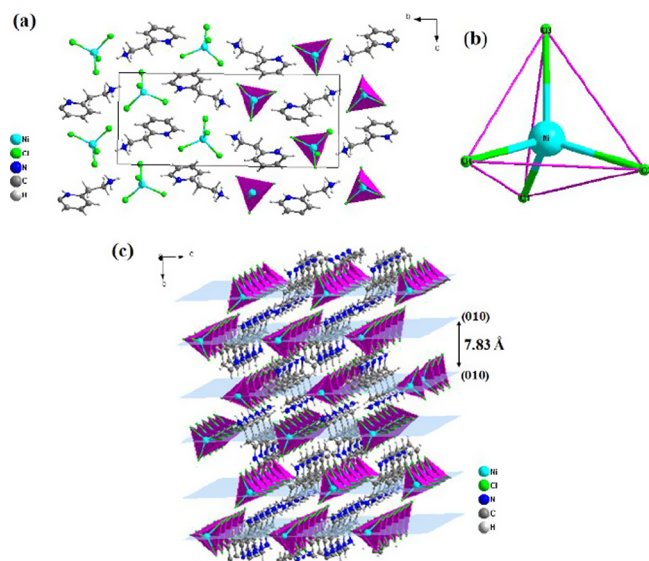


Figure 1. (a) Coordination sphere of the $[\text{NiCl}_4]^{2-}$ tetrahedron, (b) projection of the organic layers and inorganic polyhedron along the crystallographic a -axis, and (c) perspective view of the $[011]$ planes comprising $[\text{NiCl}_4]^{2-}$ anions and organic ions.

intermetallic distance of $\text{Ni-Ni} = 8.40(3) \text{ \AA}$, indicating the absence of magnetic interactions between the metal centers. It is to be noticed that the organic–inorganic layers are stacked in the $[011]$ planes with an interplane distance of 7.836 \AA (Figure 1c). Bond distances and angles are similar to those previously reported for nickel-based compounds.^{42–45}

By considering the geometrical properties, the calculated average distortion index for the Ni (II) atom is $\text{ID}_{d(\text{M-L})} = 0.0034$. This parameter (DI) is determined using the following formula:⁴⁶

$$\text{ID}_{d(\text{M-L})} = \sum_{i=1}^4 \frac{|d_i - d_m|}{4d_m} \quad (1)$$

where d_m and d_i values present the average distances and the values of the distances of the metal–ligand bonds (Ni-Cl), respectively.

The organic rings are located at $y = 1/4$ and $y = 3/4$. The values of the N–C and C–C bond lengths are in the ranges of $1.342(3)–1.488(3)$, and $1.367(3)–1.517(3) \text{ \AA}$, respectively. These average values are in accordance with those observed in similar compounds based on the organic 2-(2-aminoethyl)pyridine group.^{47–50} The interatomic distances and bond angles are listed in Table S4. We noticed that the crystal structure packing is stabilized through intermolecular C–H...Cl and N–H...Cl hydrogen bonds between organic groups and inorganic $[\text{NiCl}_4]^{2-}$ tetrahedral. The C–H...Cl distances vary from $3.437(2)$ to $3.848(2) \text{ \AA}$, while the N–H...Cl distances are between $3.176(2)$ and $3.383(2) \text{ \AA}$.

These various intermolecular hydrogen interactions give birth to a 2D framework. All hydrogen bonds are gathered in Table S5.

3.2. Thermal Stability. The crystal structure stability of the investigated sample was confirmed using TGA–DSC measurements. The TGA analysis presented in Figure 2 shows that the initial weight loss, occurring between 300 and 367 K and accounting for a mass loss of 18%, is attributed to the removal of adsorbed water molecules due to the hygroscopic nature of the sample. A similar phenomenon

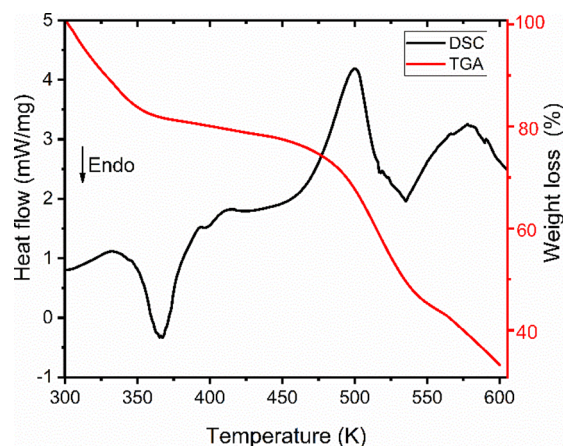


Figure 2. TGA (red line)–DSC (black line) spectra of the Ni(II)-based compound.

was observed for $[\text{N}(\text{C}_3\text{H}_7)_4]_2\text{Ni}_2\text{Cl}_6$.³⁵ The two subsequent mass losses observed between 437 and 600 K are associated with the decomposition of the polymeric network, resulting in the formation of NiO as the final residue at 598 K.

The DSC thermogram displays several distinct peaks. The first endothermic peak, observed at approximately 364 K, corresponds to the removal of adsorbed water molecules, which is attributed to the compound's hygroscopic nature. The second exothermic peak, located at around 413 K, is assigned to the phase transition of the sample. Finally, peaks around 498 and 580 K indicate the fusion of the title compound, followed by the subsequent decomposition of its polymeric network.

3.3. Optical Investigation. The room-temperature optical properties of the $(\text{C}_7\text{H}_{12}\text{N}_2)\text{NiCl}_4$ compound were investigated by recording its UV–visible absorption spectrum in the range of 280–750 nm. Figure 3a shows the normalized

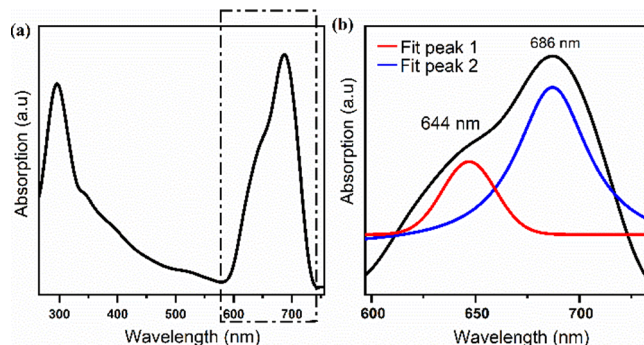


Figure 3. (a) Normalized absorption spectrum of the $(\text{C}_7\text{H}_{12}\text{N}_2)\text{-NiCl}_4$ title compound. (b) The deconvolution of the optical spectrum between 500 and 750 nm.

absorption spectrum, which exhibits a sharp peak around 296 nm, followed by a shoulder peak at 346 nm. Based on previously reported hybrid Ni(II)-based materials, the higher-energy peak at around 296 nm is attributed to the ligand-to-metal charge transfer (LMCT) excited state. On the other hand, the lower-energy peak at 346 nm can be assigned to the (MC) transition, which occurs when an electron is excited from the valence band comprising the 3p orbital of the chlorine atom to the conduction band comprising the $4s^2$ orbital of the nickel atom.^{51–53}

The deconvolution of the normalized optical spectrum (Figure 3b) in the spectral region between 500 and 750 nm reveals the presence of a shoulder peak with a maximum intensity at 644 nm, followed by a Gaussian-shaped peak at 686 nm. These features are associated with the d-d electronic transitions within the Ni²⁺ ion. Based on the Tanabe-Sugano diagram for the Ni(II) tetrahedron, two spin-allowed bands are expected. The first peak at 637 nm is associated with the transition from the ³A₂ (3F) ground term to the ³E(3F) excited state, while the second peak at around 668 nm is assigned to transitions from ³A₂(3F) ground term to the ³E(3P).⁵⁴

The optical gap energies for the Ni(II)-based hybrid material ($E_{g(d)}$ and $E_{g(ind)}$) were determined using Tauc's expression:

$$(\alpha h\nu) = B(h\nu - E_g)^n \quad (2)$$

where B is constant, E_g : the gap energy, and n : constant that defines the type of optical transition ($n = 1/2$ for the direct transition and $n = 2$ for the indirect transition).

The absorption coefficient α can be determined through the following relationship:

$$\alpha = (2.3003A)/d \quad (3)$$

where A and d represent the absorbance and the thickness of the cuvette, respectively.

The direct and indirect gap energies were determined by extrapolating the linear part of the curve to the energy-axis. Figure 4a,b depicts the dependence of $(\alpha h\nu)^{1/2}$ and $(\alpha h\nu)^2$ on

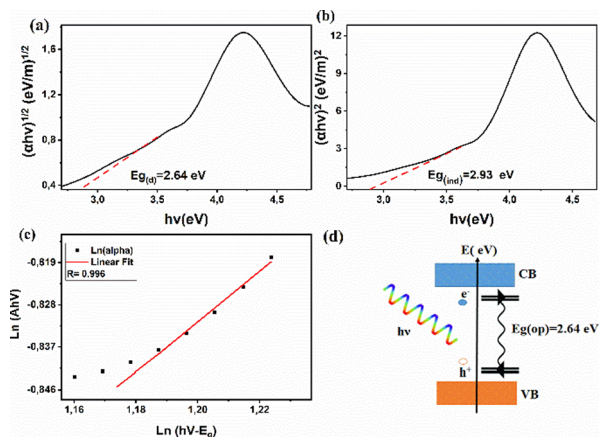


Figure 4. Plot of (a) $(\alpha h\nu)^{1/2}$ and (b) $(\alpha h\nu)^2$ versus $(h\nu)$, (c) dependence of $\ln(h\nu - E_{op})$ as a function of $\ln(Ah\nu)$, and (d) diagram the optical-absorption (OA) process within the synthesized $(C_7H_{12}N_2)$ NiCl₄ title compound.

the photon energy $h\nu$. Through this analysis, the direct and indirect gap energies were estimated to be 2.64 and 2.93 eV, respectively. In order to determine the optical gap energy E_g (op) of the title compound, a precise method was employed using the following formula:

$$n = (\ln(\alpha h\nu) \ln) / (h\nu - E_{op}) \quad (4)$$

By analysis of the $\ln(h\nu - E_{op})$ versus $\ln(Ah\nu)$ plot in Figure 4c, the slope of the curve is determined to be 0.91. This value confirms a directly allowed transition in the title compound (inset of Figure 4d). Based on these findings, the Ni(II)-based material can be classified as a semiconductor and can

effectively absorb sunlight across a wide range of wavelengths. This property is crucial for efficient energy conversion in solar cells, as it allows the material to harness a significant portion of the solar spectrum.^{55–57}

3.4. Electrical Properties. **3.4.1. Impedance Complex and Equivalent Circuit Analysis.** In order to provide valuable insight into the electrical processes and the conduction mechanism occurring within the Ni-based system, electrical properties were examined using complex impedance spectroscopy in the range 333–453 K. Figure 5a shows the Nyquist

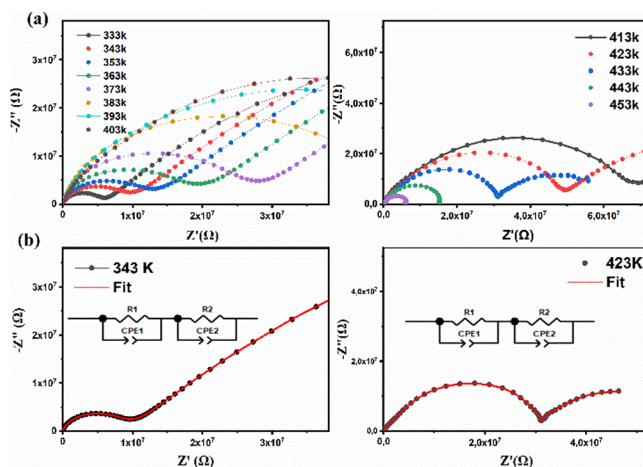


Figure 5. (a) Nyquist plots (Z' versus Z'') at various frequencies and temperatures for the investigated Ni(II)-based compound, (b) plots of the fitted impedance complex diagram at 343 and 423 K and their representative equivalent circuit.

plots (Z' versus Z'') at various temperatures. The impedance spectra exhibit some dispersion rather than a semicircle that were centered on the real axis. This dispersion indicated a non-Debye (Cole–Cole) type of relaxation. Below $T = 413$ K, the radius of the semicircle increased as the temperature rose. This behavior suggests a decrease in thermal conductivity. The following process is mainly attributed to the presence of adsorbed water molecules, which is confirmed through TGA measurements. In fact, the water molecules tend to infiltrate the grain boundary pores and act as trapping centers for charge carriers. This phenomenon is commonly observed in organic–inorganic-halide-based materials.⁵⁸

At higher temperatures (above 413 K), the Nyquist diagrams displayed a decrease in the radius of the semicircle with an increase in temperature. This trend provides clear evidence of an activated conduction process in the material, indicating enhanced conductivity as the temperature increases.^{14,19,59}

The impedance spectra plots were successfully fitted using an equivalent circuit model consisting of a combination of pure resistance (R_1) and a fractal capacitor (CPE_1) in series with a second pure resistance (R_2) and a fractal capacitor (CPE_2). The fractal capacitance (CPE) is given by the following expression:

$$Z_{CPE} = \frac{1}{Q_0(j\omega)^\alpha} = \frac{1}{(Q\omega^\alpha)\cos\left(\frac{\alpha\pi}{2}\right)} + \frac{1}{(jQ\omega^\alpha)\sin\left(\frac{\alpha\pi}{2}\right)} \quad (5)$$

The obtained results demonstrate excellent agreement between the experimental data and calculated values, providing

compelling evidence that the proposed equivalent circuit effectively describes the electrical behavior of the investigated material (Figure 5b).

The frequency-dependent variation of the real part (Z') of the complex impedance at different temperatures is depicted in Figure 6a. Notably, at lower temperatures, the amplitude of Z'

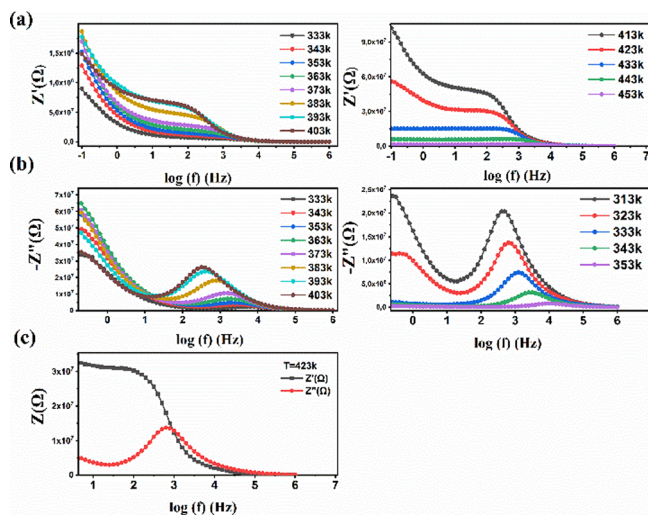


Figure 6. Frequency-dependent variation of the real part (a) (Z') and (b) of the complex impedance at different temperatures. (c) Variation of frequency as a function of the real and imaginary parts of the impedance complex (Z' and Z'') at 423 K.

is significantly higher in the low-frequency region and then gradually decreases as both temperature and frequency increase. This behavior points to enhanced DC conductivity in the title compound.

Furthermore, in the high-frequency range, all the curves converge, with Z' becoming independent of frequency. This convergence suggests the liberation of charge carriers and a subsequent reduction in barrier properties within the sample.^{60,61}

A close look at the variation of Z'' versus frequency plot (Figure 6b) shows that Z'' increases as temperature and frequency rise until reaching a maximum value Z''_{\max} , then it gradually decreases. The broadening of peaks indicates the occurrence of a relaxation process within the system.⁶¹ As the frequency decreases, all of the curves converge, indicating a potential release of charge carriers. In fact, at higher frequencies, the charge carriers have less time to relax, resulting in a decrease in polarization with increasing frequency. This behavior leads to a fusion of the curves.^{62–64}

Figure 7c illustrates the variation of the frequency as a function of the real and imaginary parts of the impedance complex (Z' and Z'') at 423 K. Notably, Z'' increases with frequency, while Z' decreases. This trend continues until Z'' reaches its maximum value (Z''_{\max}) and intersects with the Z' plot. As the frequency further increases, both Z' and Z'' decrease until they reach zero.⁶⁵

The temperature dependence of the conductivity is presented in Figure 7, where two regions are observed: one at $T > 413$ K and another at $T < 413$ K, with a noticeable change in the slope around 413 K, confirming the phase transition observed in the DSC measurements. The curve also demonstrates an increase in conductivity with rising temperatures. These findings suggest that the conduction in the

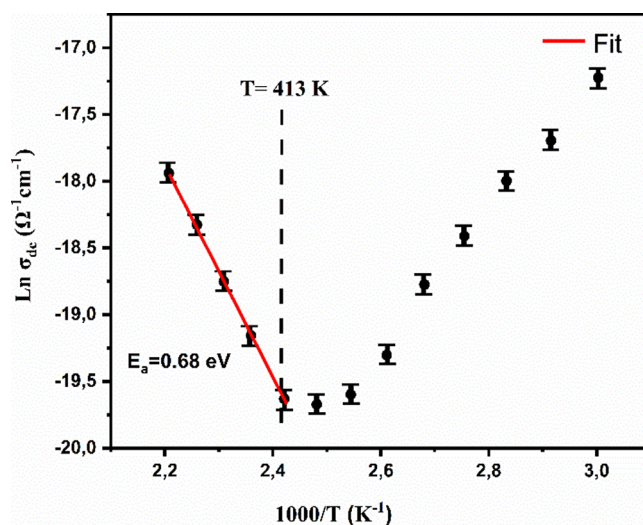


Figure 7. Variation of DC conductivity as a function of temperature.

compound follows a thermally activated transport process governed by the Arrhenius law:

$$\sigma_{dc} T = \sigma_0 \exp(-E_a/k_B T) \quad (6)$$

where; σ_0 , E_a , and k_B , represent the pre-exponential term, activation energy, and Boltzmann constant, respectively.

In region II, the activation energy is determined to be E_a (II) = 0.68 eV, indicating that the investigated compound is classified as a semiconductor material.

3.4.2. AC Conductivity. In order to study the dynamic response of the material to an applied alternating electric field, an investigation of the alternating current conductivity was conducted.

The conductivity, σ_{ac} , was calculated using the following equation:

$$\sigma_{ac} = \left(\frac{e}{s}\right) \left(\frac{Z'}{Z'^2 + Z''^2}\right) \quad (7)$$

The alternative AC conductivity is displayed as σ_{ac} vs $\log f$ (Figure 8). It is observed that the conductivity, σ_{ac} , increases

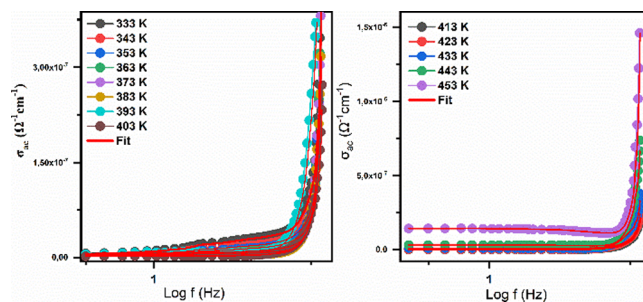


Figure 8. Variation of the alternative AC conductivity as a function of frequency for the investigated ($C_7H_{12}N_2$) $NiCl_4$ perovskite material.

with increasing temperature. Upon closer examination of the conductivity plots, two distinct regions are observed: the first region, at low frequencies, exhibits a plateau of direct current conductivity σ_{dc} , while the second region, observed at high frequencies, shows a dispersion due to interactions between charge carriers.⁶⁶ The phenomenon of conductivity dispersion, σ_{ac} , can be described by the Jonscher law:⁶⁷

$$\sigma_{ac} = \sigma_{dc} + A\omega^s \quad (8)$$

where; σ_{dc} is the DC conductivity, A : a constant that depends on the temperature, S : a parameter that measures the degree of interaction between mobile ions and its surroundings. This parameter is in the range of $[0-1]$, and ω is the angular frequency.

The plot of the exponent 's' (Figure 9) provides valuable information about the conduction mechanism. The plot reveals

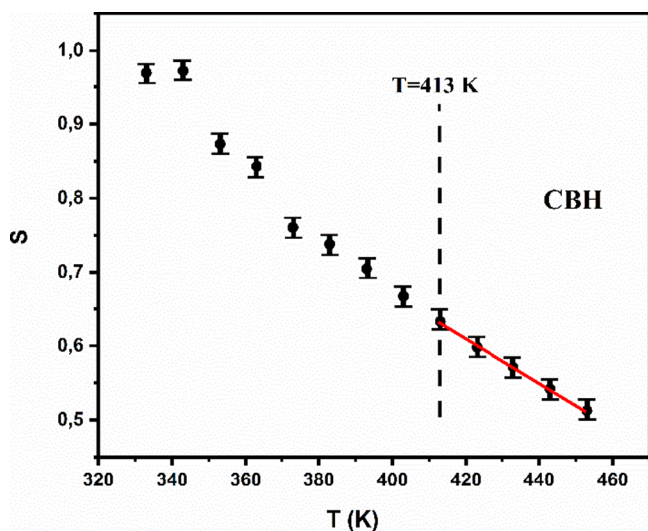


Figure 9. Plot of the exponent 's' versus temperature for the investigated nickel-based compound.

that above 413 K, the exponent 's' decreases as the temperature increases. This behavior indicates that the electrical transport process in the material is governed by the correlated barrier hopping (CBH) model.

3.4.3. Modulus Analysis. The complex modulus formalism provides insight into the electrode polarization conductivity and relaxation behavior. It serves as a valuable technique for comprehending the material's transport process and relaxation mechanism.

The complex electric modulus M^* is defined by the following equations:

$$M^* = i\omega C_0 Z^* = M' + j \quad (9)$$

where; C_0 is the capacitance vacuum. M' , M'' : present, respectively, the real and imaginary parts of the complex electrical modulus M^* .

In order to investigate the contribution of these phenomena, we have studied the variation of the real part M' of the complex modulus at different frequencies and temperatures (Figure 10a). Notably, at low frequencies, the values of M' were found to be very low, indicating that the influence of the electrodes is negligible. In this low-frequency region, the value of M' initially decreases and then gradually rises with increasing frequency. This behavior can be attributed to the fact that the electric field generated is not strong enough to provide the necessary restoring force for the movement of the charge carriers. As a result, the conduction process is primarily driven by the short-range mobility of the charge carriers. At high frequencies, M' approaches a constant value ($M'_\infty = 1/\epsilon'_\infty$), which indicates the presence of a relaxation process within the investigated Ni (II)-based material.^{68,69}

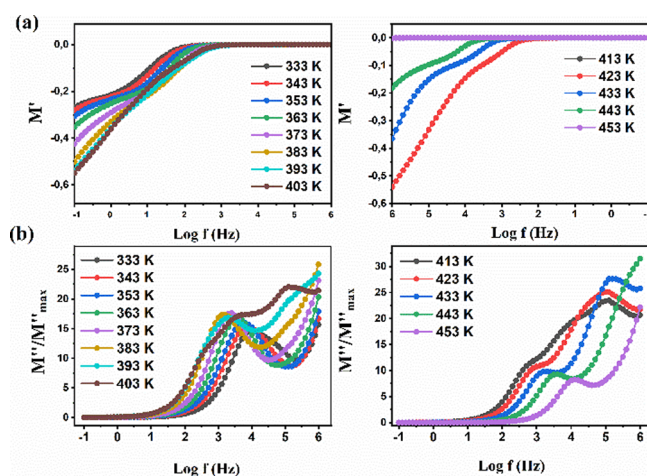


Figure 10. Variation of (a) the real part M' of the complex modulus and (b) the normalized imaginary part M''/M''_{\max} versus $\log(f)$ at different temperatures.

The 2D plots depicting the variation of the normalized imaginary part M''/M''_{\max} versus $\log(f)$ for different temperatures are shown in Figure 10b. These curves appear as asymmetric relaxation peaks, with the maximum values shifting toward higher frequencies as the temperature increases. The frequency ranges to the left of the peaks correspond to long-range movements of mobile ions. On the other hand, the frequency ranges to the right of the peaks correspond to ions that are more confined within their potential wells.

The frequency at which the maximum of the relaxation peaks (M''_{\max}) is observed indicates a transition from short-distance to long-distance movement of charge carriers as the frequency decreases.⁷⁰ We noticed that the change in the maximum value of M'' with temperature reflects a variation in capacitance. Besides, the asymmetrical broadening of the peak, indicating non-Debye-type conduction behavior, signifies the transmission of relaxation phenomena within the material.⁶⁹

3.4.4. Dielectric Measurement. To gain a deeper understanding of the material's response to electric fields and confirm the phase transitions observed in the thermal and electrical analyses, we carefully examine the variation of the permittivity. This investigation provides invaluable insights into a wide range of material properties, including ion flow, relaxation time, and electrical conductivity, within the studied material.

The real (ϵ') and imaginary (ϵ'') parts of the permittivity were determined using the following equations:⁷¹

$$\epsilon^* = \epsilon' + i\epsilon'' \quad (10)$$

$$\epsilon' = \frac{-Z''}{\omega C_0(Z'^2 + Z''^2)} \quad (11)$$

$$\epsilon'' = \frac{-Z'}{\omega C_0(Z'^2 + Z''^2)} \quad (12)$$

Figure 11a,b illustrates the temperature dependence of the real part (ϵ') and imaginary part (ϵ'') of the complex dielectric response (ϵ^*) for the Ni(II)-based compound at different frequencies. The plots clearly show that the compound undergoes a phase transition at a temperature consistent with the findings from thermal and electrical analyses.

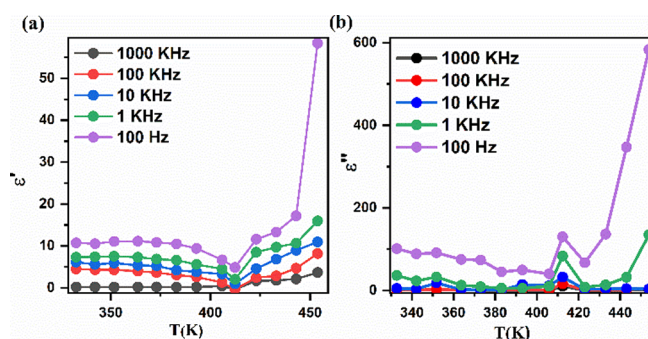


Figure 11. Temperature dependence of (a) the real part (ϵ') and (b) imaginary part (ϵ'') for the Ni(II)-based hybrid compound.

Below 413 K, both (ϵ') and (ϵ'') remain independent of temperature. However, near the phase transition temperature of 413 K, the real part of the permittivity (ϵ') exhibits an asymmetric peak, indicating a significant dielectric loss. Simultaneously, the imaginary part of the permittivity (ϵ'') reaches its maximum at this critical temperature ($T_c = 413$ K). This anomaly can be attributed to the dynamic disorder of the crystal lattice caused by the reorientation movement of the inorganic chains.^{34,37}

The frequency-dependent behavior of the real part of the permittivity (ϵ') at different temperatures is illustrated in Figure 12a. At low frequencies, it is observed that the

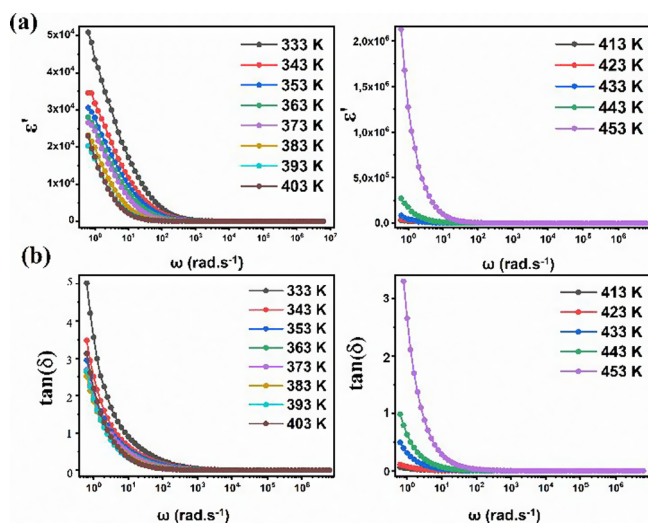


Figure 12. (a) Frequency-dependent on the real part of the permittivity (ϵ') at different temperatures. (b) The variation of the dissipation factor ($\tan(\delta)$) with frequency.

investigated sample exhibits higher (ϵ') values, reaching 10^4 , suggesting its potential as a suitable candidate for low-frequency energy storage applications. As the frequency increases, the (ϵ') values decrease, indicating an improvement in the energy storage capacity.³⁷ According to the literature, the dielectric constants of conventional semiconductors, such as inorganic compounds, are significantly lower compared to our investigated compound ($\epsilon' \sim 10^4$).^{72,73} Silicon, for instance, has a dielectric constant of 12.1,⁷⁴ while organic semiconductors typically exhibit dielectric constants ranging from 2 to 5. The reported hybrid compound ($C_6H_9N_2$)FeCl₄³⁴ exhibits substantial dielectric constants, approximately in the range of $\epsilon \sim 10^6$ at lower frequencies and demonstrates high

electrical conductivity and minimal dielectric loss at high frequencies. In fact, higher dielectric constants are associated with increased resistance to electric fields.^{34,36} Additionally, materials with high dielectric constants have the potential to enhance the performance of electronic devices. Hence, the high dielectric constant of the Ni(II) halide-based compound makes it suitable for electronic capacitor systems.

The dielectric loss ($\tan(\delta)$) is defined as the ratio of the imaginary part of the permittivity (ϵ'') to the real part of the permittivity (ϵ').^{75,76} Various physical phenomena contribute to dielectric loss, including the conduction process, dielectric relaxation, molecular dipole moment, and interfacial polarization.

The variation of the dissipation factor ($\tan(\delta)$) with frequency is shown in Figure 12b. The plots exhibit a similar trend to the variation of the real part of the permittivity (ϵ'), indicating a gradual decrease with increasing temperature and frequency.

In the low-frequency range, a higher amount of energy is required to induce the movement of charge carriers, resulting in higher ($\tan(\delta)$) values. However, as the frequency increases, the resistivity of the material decreases, leading to less energy consumption for charge carrier movement. Consequently, the dielectric loss decreases in the high-frequency region. These observations suggest that the investigated perovskite material has potential for use in electrical devices specially in the field of electronic capacitors.⁷⁷

4. CONCLUSIONS

In conclusion, a low-dimensional semiconducting Ni(II)-based hybrid compound with promising optical and electrical properties has been synthesized and extensively characterized through various techniques. The monoclinic structure packing revealed infinite layers comprising organic rings and inorganic $[NiCl_4]^{2-}$ tetrahedral, both linked by intermolecular hydrogen bonds, conferring a 2D framework. A deep investigation of the optical properties revealed an optical band gap energy of 2.6 eV, confirming the semiconductor nature of the investigated material. This finding highlights its potential for optoelectronic applications and light absorption properties, which are particularly significant for achieving high energy conversion efficiency in solar cells. The electric and dielectric properties of this material, including its high dielectric permittivity, high conductivity, and low dielectric loss, underscore its potential as an excellent material for electronic capacitors. Based on these results, we strongly believe that the research findings pave the way toward the design of novel halide-based hybrid materials that hold great promise as environmentally friendly alternatives for optical and electronic capacitor devices, potentially contributing to sustainable and cleaner technologies.

■ ASSOCIATED CONTENT

Data Availability Statement

Supplementary crystallographic data for this article are available as electronic supplementary publication from Cambridge Crystallographic Data Centre (CCDC: 2246385). This data can be obtained free of charge via <https://www.ccdc.cam.ac.uk/community/deposita> structure/CSD Communications/, or from the Cambridge Crystallographic Data Centre, 12 Union Road, Cambridge CB2 1EZ, UK (Fax: (international): + 441223/336033; email: deposit@ccdc.cam.ac.uk).

SI Supporting Information

The Supporting Information is available free of charge at <https://pubs.acs.org/doi/10.1021/acsomega.3c08499>.

Crystallographic tables and asymmetric unit of the (C₇H₁₂N₂) NiCl₄ title compound (PDF)

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Author Contributions

All authors contributed to the discussions and revisions of the manuscript. D.A.: characterization, writing, original draft, methodology, data curation, and conceptualization. I.M.: conceptualization, characterization, writing, and validation. A.O.: original draft and data curation. P.G.: validation and supervision. S.P.: validation and supervision. N.D.: validation and supervision. Z.E.: supervision, review, and methodology.

Notes

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